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## **CLAIMS**

We claim:

1. A method for creating a sloped via contact on a wafer having front and back sides, comprising:

providing a contact on the front side of the wafer;

forming a sloped via in the wafer under the front contact, the sloped via increasing in width;

coating the walls of the sloped via with conductive material; and

providing a contact on the back side of the wafer, electrically connected to the front contact through the sloped via.

- 2. The method of claim 1, wherein the sloped via is no wider than 80 um.
- 3. The method of claim 2, wherein the sloped via is no wider than 50 um.
- 4. The method of claim 2, wherein coating the walls leaves a coating of conductive material in the sloped via at least 1000 Angstroms thick where the via width is the narrowest.
- 5. The method of claim 4, wherein the conductive material is selected from the group consisting of NiChrome and gold.
- 6. The method of claim 4, wherein coating the walls includes plating.
- 7. The method of claim 2, wherein forming a sloped via includes:

forming a via; and

widening the via so that its width increases from front to back.

8. The method of claim 7, wherein forming a via includes using a deep reactive ion etching (DRIE) process.

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- 9. The method of claim 8, wherein forming a via includes using a one-sided etch.
- 10. The method of claim 8, wherein forming a via includes using a two-sided etch.
- 11. The method of claim 7, wherein widening the via includes using an isotropic plasma etch.
- 12. A sloped via contact on a wafer having front and back sides, comprising:
  - a contact on the front side of the wafer;
  - a contact on the back side of the wafer;
  - a via through the wafer connecting the front contact to the back contact, wherein

the via walls have a metal coating, and the via increases in width.

- 13. The sloped via contact as in claim 12, wherein the via is less than 80 microns at its widest.
- 14. The sloped via contact as in claim 13, wherein the via is less than 50 microns at its widest.
- 15. The sloped via contact as in claim 13 wherein the metal coating on the via is at least 1000 Angstroms thick where the via is the narrowest.
- 16. The sloped via contact as in claim 15, wherein the metal coating is selected from the group consisting of NiChrome and gold.
- 17. The sloped via contact as in claim 15, wherein the metal coating on the via is partially plated.
- 18. The sloped via contact as in claim 13, wherein the via is formed with a DRIE process.

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19. The sloped via contact as in claim 13, wherein the via is formed using a one-sided etch.

- 20. The sloped via contact as in claim 13, wherein the via is formed using a two-sided etch.
- 21. The sloped via contact as in claim 13, wherein the slope of the via walls is not constant.
- 22. The sloped via contact as in claim 13, wherein the via walls are curved.